

Direct Attach DA3547[™] LEDs CxxxDA3547-Sxxx00 Data Sheet

Cree's Direct Attach DA3547 LEDs are the next generation of solid-state LED emitters that combine highly efficient InGaN materials with Cree's proprietary device technology and silicon-carbide substrates to deliver superior value for the TV-backlighting and general-illumination markets. The DA3547 LEDs are among the brightest in the top-view market while delivering a low forward voltage, resulting in a very bright and highly efficient solution. The bondpaddown design allows for eutectic die attach, eliminating the need for wire bonds, and enables superior performance from improved thermal management. The design is optimally suited for industry-standard top-view packages.

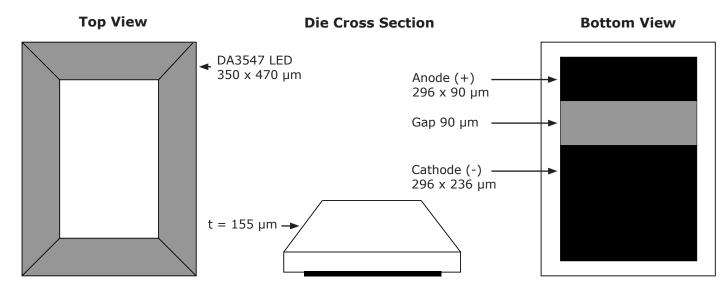
FEATURES

- Rectangular LED RF Performance
 - 450 & 460 nm 76 mW min
- High Reliability Eutectic Attach
- Low Forward Voltage (Vf) 3.1 V Typical at 50 mA
- Maximum DC Forward Current 150 mA
- 1000-V ESD Threshold Rating
- InGaN Junction-Down Design for Improved Thermal
 Management
- No Wire Bonds Required

APPLICATIONS

- Large LCD Backlighting
 - Television
- General Illumination
- Medium LCD Backlighting
 - Portable PCs
 - Monitors
- LED Video Displays
- White LEDs

CxxxDA3547-Sxxx00 Chip Diagram



Subject to change without notice. www.cree.com



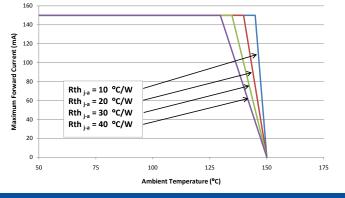
Maximum Ratings at T _A = 25°C ^{Notes 1,3, & 4}	CxxxDA3547-Sxxx00
DC Forward Current	150 mA
Peak Forward Current (1/10 duty cycle @ 1 kHz)	200 mA
LED Junction Temperature	150°C
Reverse Voltage	5 V
Operating Temperature Range	-40°C to +100°C
Storage Temperature Range	-40°C to +100°C
Electrostatic Discharge Threshold (HBM) Note 2	1000 V
Electrostatic Discharge Classification (MIL-STD-883E) Note 2	Class 2

Typical Electrical/Optical Characteristics at T _A = 25°C, If = 50 mA Note 3									
Part Number	Forward Voltage (V _f , V)		(V _f , V)	Reverse Current [I(Vr=5V), μA]	Full Width Half Max (λ _p , nm)				
	Min.	Тур.	Max.	Max.	Тур.				
C450DA3547-Sxxx00	2.8	3.1	3.4	2	20				
C460DA3547-Sxxx00	2.8	3.1	3.4	2	21				

Mechanical Specifications	CxxxDA3547-Sxxx00		
Description	Dimension	Tolerance	
P-N Junction Area (µm)	296 x 416	±35	
Chip Bottom Area (µm)	350 x 470	±35	
Chip Top Area (µm)	200 x 320	±35	
Chip Thickness (µm)	155	±15	
AuSn Bond Pad Width – Anode (um)	90	±15	
AuSn Bond Pad Length – Anode (um)	296	±35	
AuSn Bond Pad Width – Cathode (um)	236	±35	
AuSn Bond Pad Length – Cathode (um)	296	±35	
Bond Pad Gap (µm)	90	±15	
AuSn Bond Pad Thickness (µm)	3	±0.5	

Notes:

- 1. Maximum ratings are package-dependent. The above ratings were determined using a chip sub-mount on MCPCB (with silicone encapsulation and intrinsic AuSn metal die attach) for characterization. Ratings for other packages may differ. Junction temperature should be characterized in a specific package to determine limitations. Assembly processing temperature must not exceed 325°C (< 5 seconds).
- 2. Product resistance to electrostatic discharge (ESD) according to the HBM is measured by simulating ESD using a rapid avalanche energy test (RAET). The RAET procedures are designed to approximate the maximum ESD ratings shown.
- 3. All products conform to the listed minimum and maximum specifications for electrical and optical characteristics when assembled and operated at 50 mA within the maximum ratings shown above. Efficiency decreases at higher currents. Typical values given are within the range of average values expected by manufacturer in large quantities and are provided for information only. All measurements were made using lamps in T-1 3/4 packages (with Hysol OS4000 epoxy encapsulant and intrinsic AuSn metal die attach). Optical characteristics measured in an integrating sphere using Illuminance E.
- 4. The maximum forward current is determined by the thermal resistance between the LED junction and ambient. It is crucial for the end-product to be designed in a manner that minimizes the thermal resistance from the LED junction to ambient in order to optimize product performance.



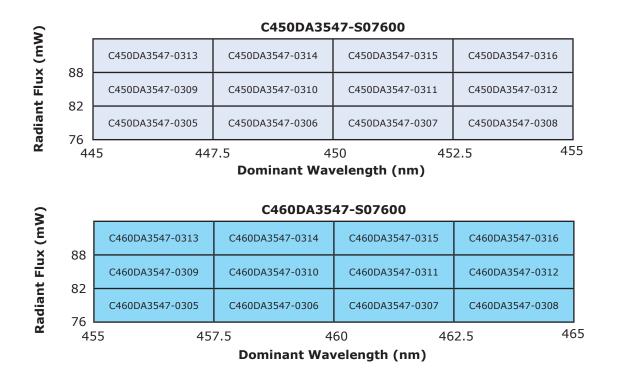
Copyright © 2010 Cree, Inc. All rights reserved. The information in this document is subject to change without notice. Cree and the Cree logo are registered trademarks, and DA and DA3547 are trademarks of Cree, Inc.

Cree, Inc. 4600 Silicon Drive Durham, NC 27703 USA Tel: +1.919.313.5300 www.cree.com



Standard Bins for CxxxDA3547-Sxxx00

LED chips are sorted to the **radiant flux** and **dominant wavelength** bins shown. A sorted die sheet contains die from only one bin. Sorted die kit (CxxxDA3547-Sxxxxx) orders may be filled with any or all bins (CxxxDA3547-xxxxx) contained in the kit. All radiant flux and dominant wavelength values shown and specified are at If = 50 mA.



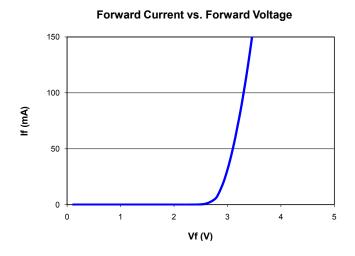
Cree, Inc. 4600 Silicon Drive Durham, NC 27703 USA Tel: +1.919.313.5300 www.cree.com

Copyright © 2010 Cree, Inc. All rights reserved. The information in this document is subject to change without notice. Cree and the Cree logo are registered trademarks, and DA and DA3547 are trademarks of Cree, Inc.



Characteristic Curves

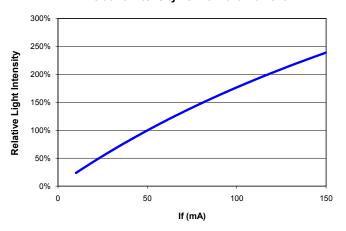
These are representative measurements for the DA LED product. Actual curves will vary slightly for the various radiant flux and dominant wavelength bins.



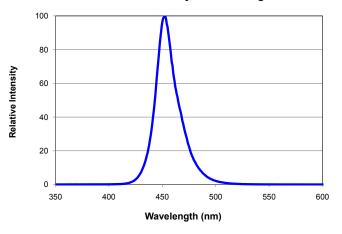
Output Maveleugh Shift (un)

Wavelength Shift vs. Forward Current

Relative Intensity vs. Forward Current



Relative Intensity vs. Wavelength



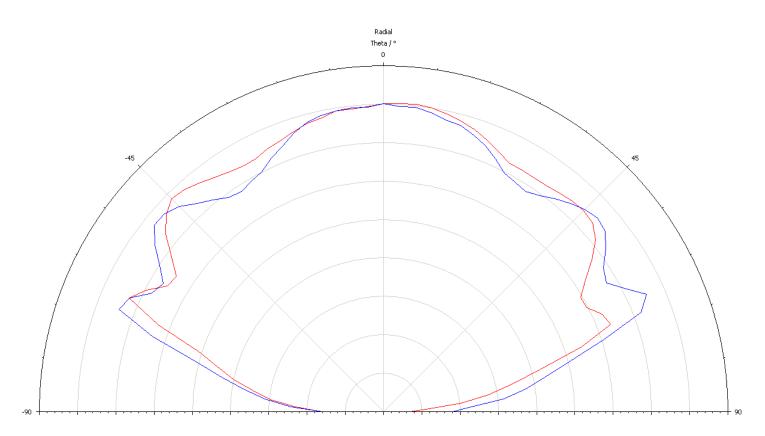
Copyright © 2010 Cree, Inc. All rights reserved. The information in this document is subject to change without notice. Cree and the Cree logo are registered trademarks, and DA and DA3547 are trademarks of Cree, Inc.

Cree, Inc. 4600 Silicon Drive Durham, NC 27703 USA Tel: +1.919.313.5300 www.cree.com



Radiation Pattern

This is a representative radiation pattern for the DA LED product. Actual patterns will vary slightly for each chip.



Copyright © 2010 Cree, Inc. All rights reserved. The information in this document is subject to change without notice. Cree and the Cree logo are registered trademarks, and DA and DA3547 are trademarks of Cree, Inc.

Cree, Inc. 4600 Silicon Drive Durham, NC 27703 USA Tel: +1.919.313.5300 www.cree.com